

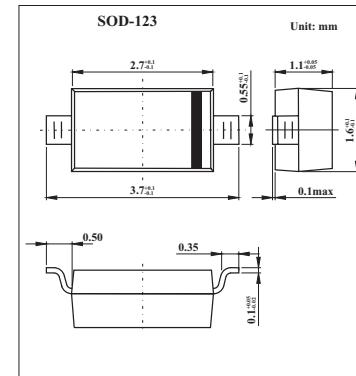
Schottky Rectifier Diodes

KBR0520LW/0530W/0540W

(MBR0520LW/0530W/0540W)

■ Features

- Low forward voltage drop
- Guard ring construction for Transient protection.
- High conductance.
- Also available in lead free version.



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	KBR0520LW	KBR0530W	KBR0540W	Unit
Peak repetitive peak reverse voltage	V _{RRM}				
Working peak reverse voltage	V _{RWM}	20	30	40	V
DC blocking voltage	V _R				
RMS reverse voltage	V _{R(RMS)}	14	21	28	V
Average rectified output current	I _O		500		mA
Peak forward surge current	I _{FSM}		5.5		A
Power dissipation	P _d		410		mW
Voltage rate of change	dV/dt		1000		V/μs
Thermal resistance junction to ambient	R _{θJA}		304		°C/W
Storage temperature	T _{stg}		-65 to +125		°C

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Minimum Reverse Breakdown Voltage	V _{(BR)R}	I _R =250 μA	20			V
		I _R =200 μA	30			
		I _R =20 μA	40			
Forward voltage	V _{F1}	I _F =0.1A	0.3			V
			0.375			
Forward voltage	V _{F2}	I _F =0.5A	0.375			V
			0.430			
			0.510			
Forward voltage	V _{F3}	I _F =1A	0.62			V
Reverse current	I _{R1}	V _R =10V	75			μA
		V _R =15V	20			μA
Reverse current	I _{R3}	V _R =20V	250			μA
		V _R =30V	10			μA
Reverse current	I _{R4}	V _R =30V	130			μA
		V _R =40V	20			μA
Capacitance between terminals	C _T	V _R =0V, f=1MHz	170			pF

■ Marking

NO.	KBR0520LW	KBR0530W	KBR0540W
Marking	SD	SE	SF

**KBR0520LW/0530W/0540W
(MBR0520LW/0530W/0540W)**

■ Typical Characteristics

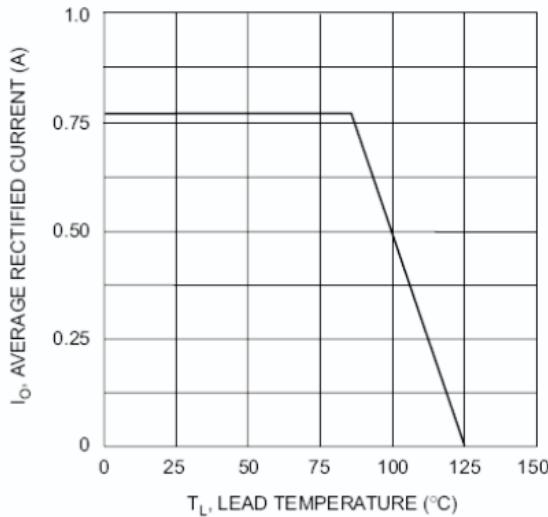


Fig.1 Forward Current Derating Curve

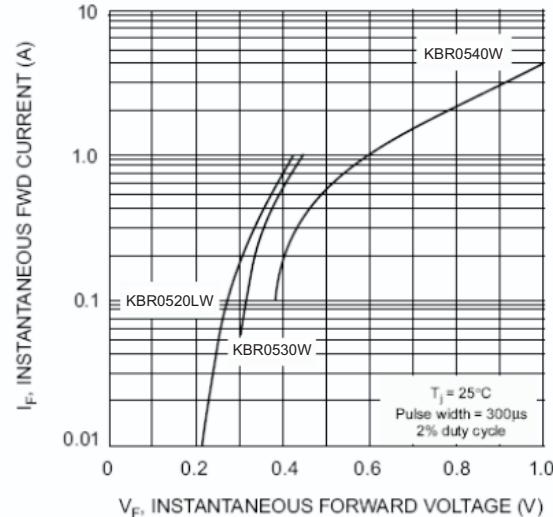


Fig.2 Typical Forward Characteristics

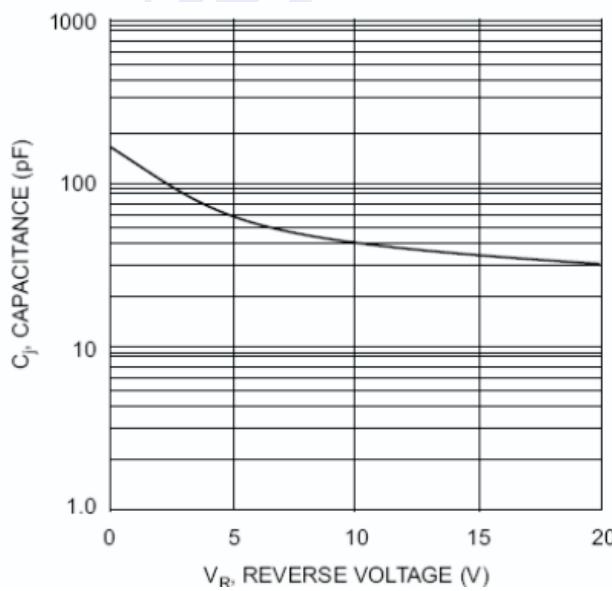


Fig.3 Typ.Junction Capacitance vs Reverse Voltage